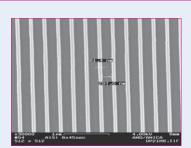
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# **UV-curable polymers for UV-based nanoimprint lithography**

#### mr-UVCur21 and mr-UVCur06 – fast curing polymer systems for pattern transfer



80 nm lines imprinted in mr-UVCur21, pattern depth 110 nm (Courtesy of AMO)

| 1000 0000 1m |
|--------------|

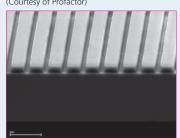
Excellent filling of mould patterns with demanding filling factors, 100x100  $\mu m^2$  squares, mr-UVCur21 (Courtesy of AMO)



Imprinted lines, sub-30 nm resolution (Courtesy of AMO)



800 nm squares, 1200 nm pitch, imprinted in mr-UVCur06, large-area imprint (Courtesy of Profactor)

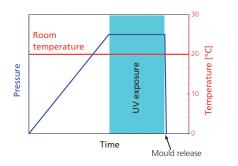


350 nm trenches, mr-UVCur06, residual layer thickness < 10 nm (Courtesy of Profactor)

k 02 09 19 0

#### Attributes

- <sup>–</sup> Compatibility with various nanoimprint tools:
- <sup>-</sup> Wafer-scale or step&repeat UV-imprints
- <sup>-</sup> Imprinting in vacuum or under atmospheric pressure
- <sup>–</sup> Excellent film quality and thickness uniformity
- Short cycle times due to fast filling of mould cavities
- Pattern resolution below 30 nm (mr-UVCur21, limited by the mould, not by the polymer)
- <sup>-</sup> Very low residual layer thickness (< 10 nm)
- Short curing times, low UV doses, compatibility with various UV lamps and filter systems
- High plasma etch resistance, no residues after oxygen plasma etching (silicon-free polymer)
- <sup>–</sup> Appropriate adhesion promoter available



## **Technical Data**

| UV-curable Polymer   | mr-UVCur06   | mr-UVCur21              | mr-UVCur21SF                |  |
|--|--|-------------------------|-----------------------------|--|
| Coating method   | Spin coating   | Spin coating            | Dispensing,<br>spin coating |  |
| Process conditions   | Imprint: room temperature process, low imprint pressures<br>(>100 mbar), imprint in vacuum or under atmospheric pressure<br>UV exposure: broad band or i-line, curing time few seconds |                         |                             |  |
| Smallest feature size<br>Aspect ratio                                    | 50 nm<br>< 2   | < 30 nm<br>> 2          | < 30 nm<br>> 2              |  |
| Ready-to-use solutions<br>for various film thick-<br>nesses * (3000 rpm) | 240 nm   | 100nm<br>200nm<br>300nm | 1.6 µm<br>(spin coating)    |  |
| Diluents   | mr-T 1070  | mr-T 1070               | mr-T 1070                   |  |
| Adhesion Promoter  | mr-APS1  | mr-APS1                 | mr-APS1                     |  |

#### \* Different film thicknesses are available on request for mr-UVCur21

# Applications

- Etch mask for pattern transfer processes (dry and wet etching)
- <sup>–</sup> Fabrication of nanopatterns
  - <sup>-</sup> Data storage
  - Nano-optical devices,
  - sub-wavelength optical elements
  - <sup>–</sup> Photonic crystals
  - <sup>-</sup> Micro- and Nanofluidics
  - <sup>-</sup> Microelectronics
- <sup>–</sup> Coating of various substrate materials, e.g. Si, SiO<sub>2</sub>, Al

### **Process Flow**

